1.5MHz, 3A, 5V Input Synchronous Step-Down Converter

FEATURES

- High Efficiency: Up to 96% at 5V to 3.3V
- 1.5MHz Switching Frequency
- Up to 3A Output Current
- No Schottky Diode Required
- 2.7V to 5.5V Input Voltage Range
- Output Voltage as Low as 0.6V
- PFM Mode for High Efficiency in Light Load
- 100% Duty Cycle in Dropout Operation
- Low Quiescent Current: 50μA
- Short Circuit Protection
- Thermal Shutdown Protection
- Power Good Output Function
- Inrush Current Limit and Soft Start
- Input overvoltage protection (OVP)
- TMI3113H2: SOT23-6 package
- TMI3113H2D: DFN2x2-8 package

APPLICATIONS

- Solid State Drive
- Wireless and DSL Modems
- Portable Instruments
- Digital and Video Cameras

GENERAL DESCRIPTION

The TMI3113H2 and TMI3113H2D are 1.5MHz constant frequency, current mode step-down converter with fast load transient response. They are ideal for portable equipment requiring high output current up to 3A from single-cell Lithium-ion batteries. The device also can run at 100% duty cycle for low dropout operation, extending battery life in portable systems while light load operation provides very low output ripple for noise sensitive applications. The 1.5MHz switching frequency of TMI3113H2 and TMI3113H2D could minimize the size of external components while keeping switching losses low. The internal slope compensation setting allows the device to operate with smaller inductor values to optimize size and provide efficient operation. TMI3113H2 and TMI3113H2D have power good function.

The devices offer two operation modes, PWM control and PFM Mode switching control, which allow a high efficiency over the wider range of the load. They have cycle-by-cycle peak current limit to protect over load and short condition.

TYPICAL APPILCATION

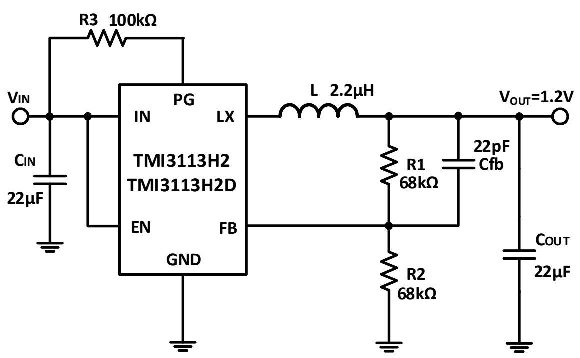
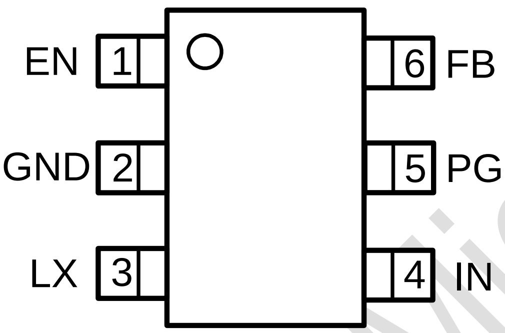


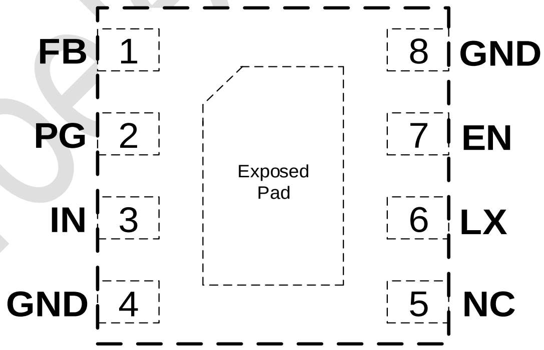
Figure 1. Typical Application Circuit

ABSOLUTE MAXIMUM RATINGS (Note 1)

Parameter	Min	Max	Unit
Input Supply Voltage	-0.3	7	V
LX Voltages	-0.3	7	V
LX Voltages (<10ns transient)	-2.5	7.5	V
LX Voltages (<5ns transient)	-3.5	8.5	V
EN, FB, PG Voltage	-0.3	7	V
Storage Temperature Range	-65	150	°C
Junction Temperature (Note2)	-	160	°C
Power Dissipation (SOT23-6)	-	1	W
Power Dissipation (DFN2x2-8)		2.6	W
Lead Temperature (Soldering, 10s)	-	260	°C

PACKAGE/ORDER INFORMATION





SOT23-6 (Top View)

DFN2x2-8 (Top View)

Top Mark: THBXXX (THB: Device Code, XXX: Inside Code) for TMI3113H2
Top Mark: THDXXX (THD: Device Code, XXX: Inside Code) for TMI3113H2D

Part Number	Package	Top mark	Quantity/ Reel
TMI3113H2	SOT23-6	THBXXX	3000
TMI3113H2D	DFN2x2-8	THDXXX	3000

TMI3113H2 and TMI3113H2D devices are Pb-free and RoHS compliant.

PIN DESCRIPTIONS

Pin		Name	Function
TMI3113H2	TMI3113H2D		
1	7	EN	Enable Pin. Drive EN above 1.5V to turn on the part. Drive EN below 0.4V to turn it off. Do not leave EN floating.
2	4/8	GND	Ground pin.
3	6	LX	Power Switch Output. It is the switch node connection to Inductor. This pin connects to the drains of the internal P-ch and N-ch MOSFET switches.
4	3	IN	Analog Supply Input Pin.
5	2	PG	Power Good Open Drain Output Pin.
6	1	FB	Output Voltage Feedback Pin. An internal resistive divider divides the output voltage down for comparison to the internal reference voltage.

ESD RATING

Items	Description	Value	Unit
V_{ESD_HBM}	Human Body Model for all pins	±2000	V
V_{ESD_CDM}	Charge Device Model for all pins	±1000	V

JEDEC specification JS-001

RECOMMENDED OPERATING CONDITIONS

Items	Description	Min	Max	Unit
Voltage Range	IN	2.7	5.5	V
T_J	Operating Junction Temperature Range	-40	125	°C
T_A	Operating Ambient Temperature Range	-40	85	°C

THERMAL RESISTANCE

Items	Description	Value	Unit
θ_{JA}	Junction-to-ambient thermal resistance of SOT23-6	130	°C/W
	Junction-to-ambient thermal resistance of DFN2x2-8	52	°C/W
θ_{JC}	Junction-to-case(top) thermal resistance of SOT23-6	56	°C/W
	Junction-to-case(bottom) thermal resistance of DFN2x2-8	12	°C/W

ELECTRICAL CHARACTERISTICS

(V_{IN}=V_{EN}=3.6V, V_{OUT}=1.8V, T_A = 25°C, unless otherwise noted.)

Parameter	Conditions	Min	Typ	Max	Unit
Input Voltage Range		2.7		5.5	V
Input OVP Threshold	V_{IN} Rising		6.1		V
Input UVLO Threshold	V_{IN} Rising		2.5		V
Input UVLO Hysteresis			0.5		V
Quiescent Current	V_{EN} =2.0V, I_{OUT}=0A V_{FB}=V_{REF} x 105%		50	85	µA
Shutdown Current	V_{EN} = 0V		0.1	1.0	µA
Regulated Feedback Voltage V_{FB}	PWM operation, T_A = 25°C	0.588	0.600	0.612	V
	PFM operation, No Load, T_A = 25°C		0.609		V
Oscillation Frequency	V_{OUT}=1.8V		1.5		MHz
	V_{OUT}=0V		475		kHz
On Resistance of PMOS	I_{LX}=100mA		95		mΩ
On Resistance of NMOS	I_{LX}=-100mA		50		mΩ
Peak Current Limit	V_{IN}= 5V, V_{FB}=90%*V_{REF}		4		A
EN High Level Input Voltage		1.5			V
EN Low Level Input Voltage				0.4	V
EN Leakage Current			±0.01	±1.0	µA
Power Good Threshold	V_{FB} Reference to V_{REF} voltage		91%		
Power Good Sink Current				2	mA
LX Leakage Current	V_{EN} = 0V, V_{IN} = V_{LX} = 5V		±0.01	±1.0	µA
Thermal Shutdown Threshold (Note 3)			155		°C
Thermal Shutdown Hysteresis (Note 3)			20		°C

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired. **Note 2**: T_J is calculated from the ambient temperature T_A and power dissipation P_D according to the following formula: $T_J = T_A + (P_D) \times \theta_{JA}$.

Note 3: Thermal shutdown threshold and hysteresis are guaranteed by design.

OPERATION

Overview

The TMI3113H2 and TMI3113H2D are high output current monolithic switch mode step-down DC-DC converter. The devices operate at a fixed 1.5MHz switching frequency, and uses a slope compensated current mode architecture.

The step-down DC-DC converters can supply up to 3A output current and has an input voltage range from 2.7V to 5.5V. It minimizes external component size and optimizes efficiency at the heavy load range. The slope compensation allows the device to remain stable over a wider range of inductor values so that smaller values with lower DCR can be used to achieve higher efficiency. Only a small bypass input capacitor is required at the output.

In light and no load condition, TMI3113H2 and TMI3113H2D are operating in PFM mode for power saving. In PFM mode, the devices ramp up its output voltage with several SW switching pulse, while the error amplifier output voltage V_{COMP} drops. The devices stop switching when V_{COMP} voltage drops down the inner threshold, so the FB voltage in PFM mode is a little bit higher than normal 0.6V reference voltage in PWM operation. In no load condition, FB voltage is typically 1.5% higher than normal 0.6V reference voltage.

The adjustable output voltage can be programmed with external feedback dividers, ranging from 0.6V to near the input voltage. The devices use internal MOSFETs to achieve high efficiency and can generate very low output voltages by using an internal reference of 0.6V. At dropout operation, the converter duty cycle increases to 100% and the output voltage tracks the input voltage minus the low $R_{DS(ON)}$ drop of the P-channel high-side MOSFET and the inductor DCR. The internal error amplifier and compensation provides excellent transient response, load and line regulation. Internal soft start eliminates any output voltage overshoot when the device is enabled or the input voltage is applied.

Input Over Voltage Protection

TMI3113H2 and TMI3113H2D have input side over voltage protection function. When input voltage is higher than input OVP threshold 6.1V typical, TMI3113H2 and TMI3113H2D stop switching operation to protect device to work with high input voltage. When input voltage is recovered from OVP and drops down input OVP threshold with OVP hysteresis typical 180mV, the devices start to switch as normal operation automatically. This function protects device from switching in abnormal high input voltage and input surge condition.

Input Under Voltage Lockout

TMI3113H2 and TMI3113H2D implement input under voltage lockout function to avoid mis-operation at low input voltages. When the input voltage is lower than input UVLO threshold with UVLO hysteresis, the device is shut down. The typical 500mV input UVLO hysteresis value of TMI3113H2 and TMI3113H2D are useful to prevent device from abnormal switching caused by input voltage oscillation around UVLO threshold during input voltage power-up and power-down with high load condition.

Soft Start

TMI3113H2 and TMI3113H2D have built-in soft-start circuits to control output voltage rise rate to avoids excessive inrush current during IC start up. The typical soft-start time is 1ms.

Over Current Limit and Output Short Protection

TMI3113H2 and TMI3113H2D have high side switching current limit function and prevents the device from high load current condition. The typical high side peak current limit value is 4A. When output load current increases and inductor current peak value reaches peak current limit value, high side MOSFET is turned off immediately and the output voltage drops down according to load condition. If output voltage keeps falling down, once the VFB voltage is lower than 300mV typical, the device enters into output short protection condition. In output short protection condition, the switching frequency of TMI3113H2 decreases from 1.5MHz to 475kHz and the peak current limit value reduces from 4A to 3.6A typically in order to reduce power consumption and device thermal rise in the condition of output short to GND.

Thermal Shutdown

TMI3113H2 and TMI3113H2D enter into thermal shutdown once the junction temperature exceeds thermal shutdown threshold 155°C typically. Once the device junction temperature falls below the threshold with hysteresis, TMI3113H2 and TMI3113H2D return to normal operation automatically.

Power Good

TMI3113H2 and TMI3113H2D also have power good open drain output to indicate output voltage status. When input voltage is higher than UVLO and EN is enabled, PG status is determined by output voltage. The PG pin goes high impedance when the output is above 91% of regulated nominal voltage and PG pin is pulled low once output voltage falls below the threshold. When the device is shut down by EN pulling low, the PG is pulled low as well.

FUNCTIONAL BLOCK DIAGRAM

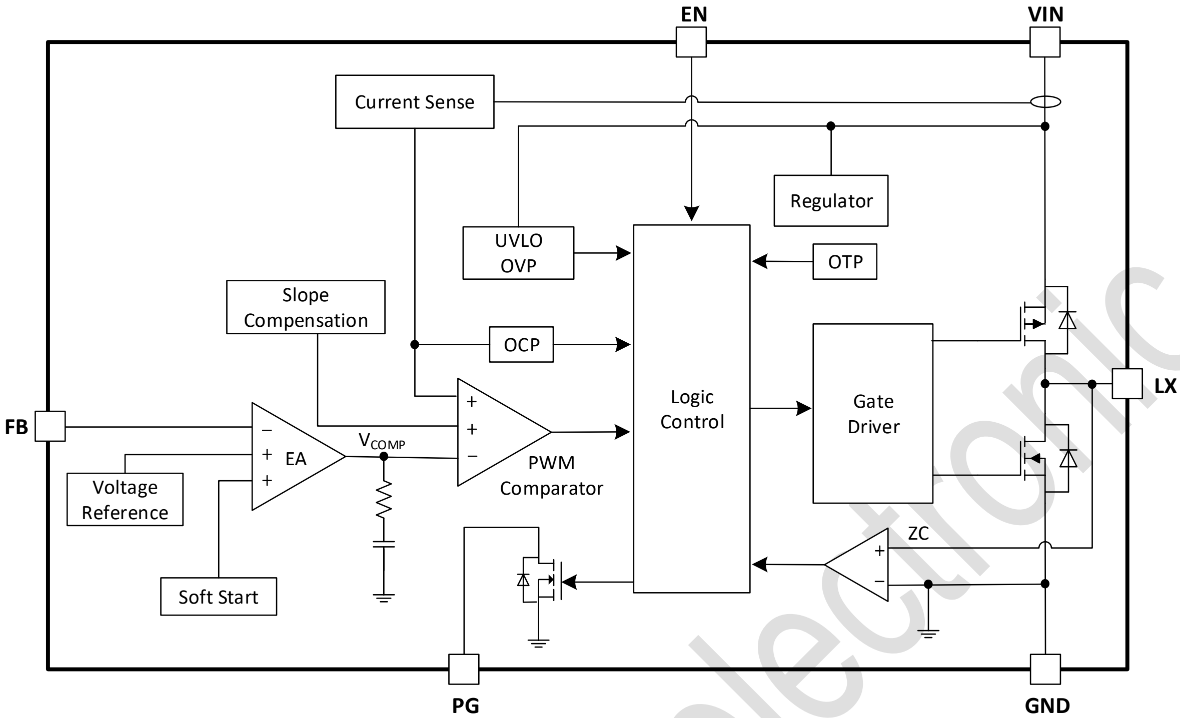


Figure 2. TMI3113H2 and TMI3113H2D Block Diagram

APPLICATION INFORMATION

Setting the Output Voltage

In the first page, the typical application circuit for the TMI3113H2 and TMI3113H2D are shown. The output voltage of TMI3113H2 and TMI3113H2D can be externally programmed. Resistors R1 and R2 in typical application program the output to regulate at a voltage higher than 0.6V.

The external resistor sets the output voltage according to the following equation:

$$V_{OUT} = 0.6 \times (1 + \frac{R_1}{R_2})$$

$$R_1 = (V_{OUT} / 0.6 - 1) \times R_2$$

Inductor Selection

For most designs, 2.2μH inductance can satisfy most application conditions. Inductance value is related to inductor ripple current value, input voltage, output voltage setting and switching frequency. The inductor value can be derived from the following equation:

$$L = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times \Delta I_L \times f_{OSC}}$$

Where ΔI_L is inductor ripple current. Large value inductors result in lower ripple current and small value inductors result in high ripple current, so inductor value has effect on output voltage ripple value. DC resistance of inductor which has impact on efficiency of DC/DC converter should be taken into account when selecting the inductor.

Input Capacitor Selection

The input capacitor reduces the surge current drawn from the input and switching noise from the device. The input capacitor impedance at the switching frequency should be less than input source impedance to prevent high frequency switching current passing to the input. A low ESR input capacitor sized for maximum RMS current must be used. Ceramic capacitors with X5R or X7R dielectrics are highly recommended because of their low ESR and small temperature coefficients. A 22μF effective capacitance value ceramic capacitor for most applications is sufficient. A large value may be used for improved input voltage filtering.

Output Capacitor Selection

The output capacitor is required to keep the output voltage ripple small and to ensure regulation loop stability. The output capacitor must have low impedance at the switching frequency. Ceramic capacitors with X5R or X7R dielectrics are recommended due to their low ESR and high ripple current ratings. The output ripple △VOUT is determined by:

$$\Delta V_{OUT} \leq \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times f_{OSC} \times L} \times \left(ESR + \frac{1}{8 \times f_{osc} \times C3} \right)$$

A 22μF effective capacitance value ceramic capacitor can satisfy most applications.

Layout Consideration

When laying out the printed circuit board, the following checking should be used to ensure proper operation of the TMI3113H2 and TMI3113H2D. Check the following in your layout:

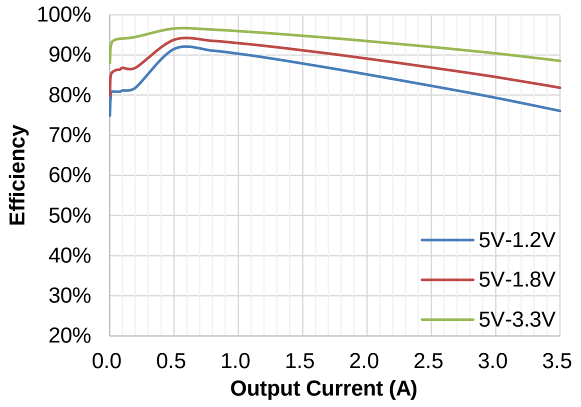
1. The power traces, consisting of the GND trace, the LX trace and the VIN trace should be kept short, direct and wide.
2. Does the (+) plates of C_{IN} connect to Vin as closely as possible. This capacitor provides the AC current to the internal power MOSFETs.
3. Keep the switching node, LX, away from the sensitive FB node.
4. Keep the (-) plates of C_{IN} and C_{OUT} as close as possible.

TYPICAL PERFORMANCE CHARACTERISTICS

V_{IN}=5V, V_{OUT}=1.2V, C_{IN}=22µF, C_{OUT}=22µF, L=2.2µH, T_A=25°C, TMI3113H2, unless otherwise noted

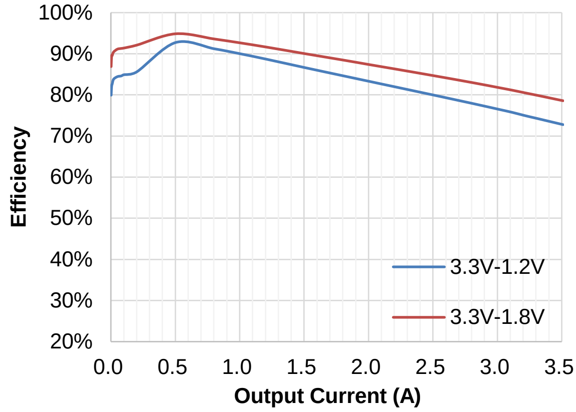
Efficiency at V_{IN} = 5V

V_{IN} =5V, L=2.2µH, DCR=20mΩ



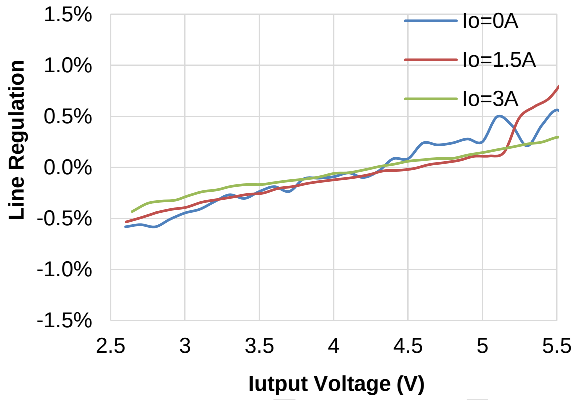
Efficiency at V_{IN} = 3.3V

V_{IN} =3.3V, L=2.2µH, DCR=20mΩ



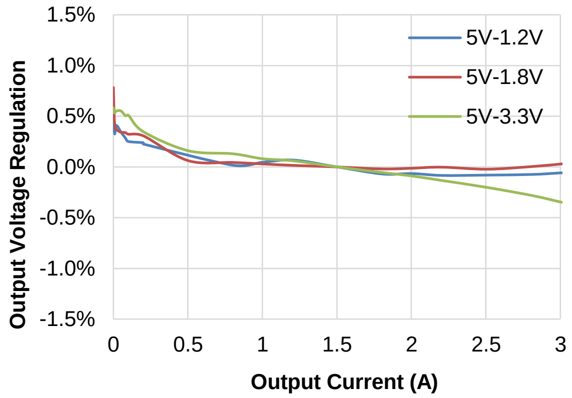
Line Regulation at V_{OUT}=1.2V

V_{OUT}=1.2V, T_A=25°C



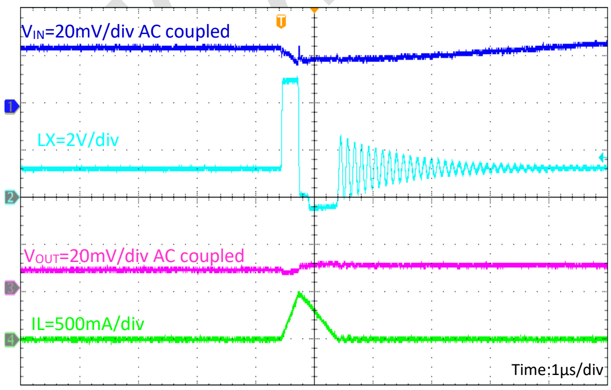
Load Regulation at V_{IN} = 5V

V_{IN}=5V, T_A=25°C



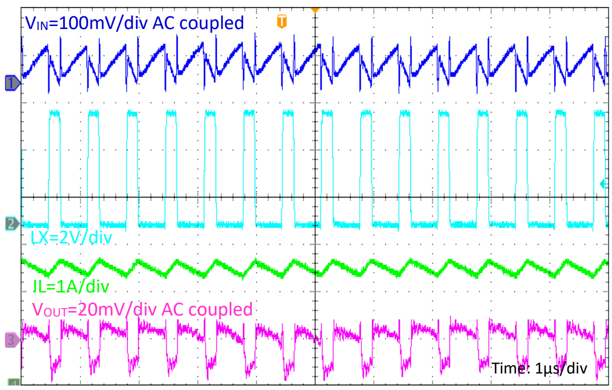
Steady State Operation

V_{IN} =5V, V_{OUT} =1.2V, No Load



Steady State Operation

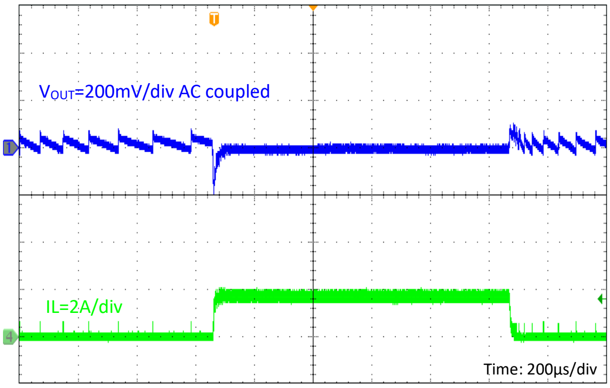
V_{IN} =5V, V_{OUT} =1.2V, I_o=3A



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

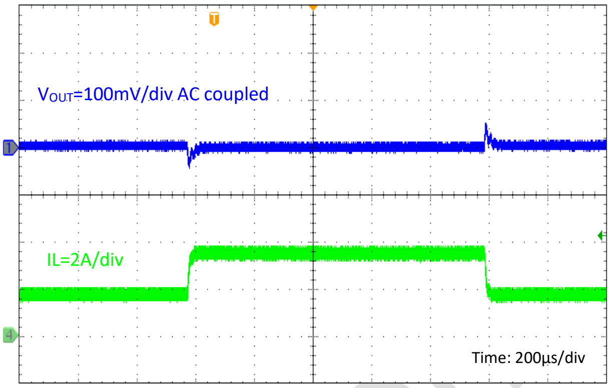
Load Transient

V_{IN} =5V, V_{OUT} =1.2V, I_o = 0A to 3.5A



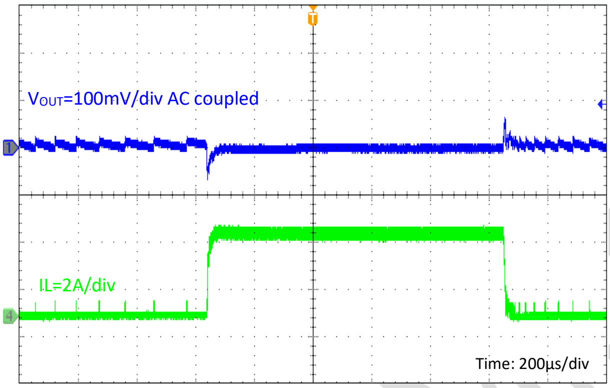
Load Transient

V_{IN} =5V, V_{OUT} =1.2V, I_o = 0.35A to 3.15A



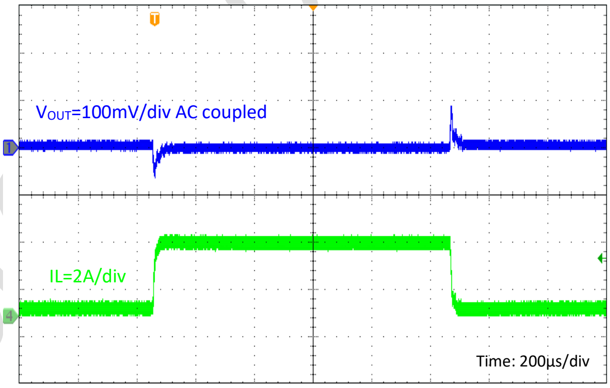
Load Transient

V_{IN} =5V, V_{OUT} =1.2V, I_o = 0A to 1.75A



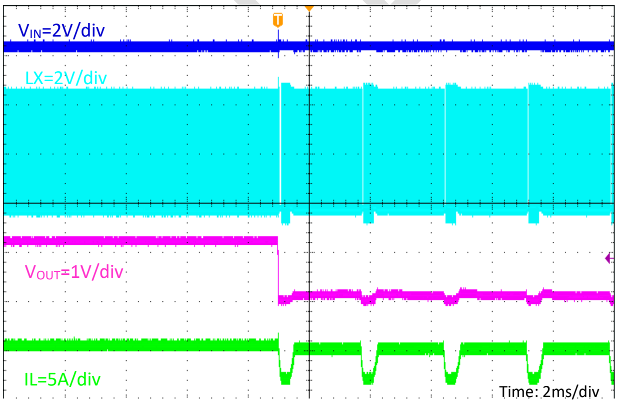
Load Transient

V_{IN} =5V, V_{OUT} =1.2V, I_o = 1.75A to 3.5A



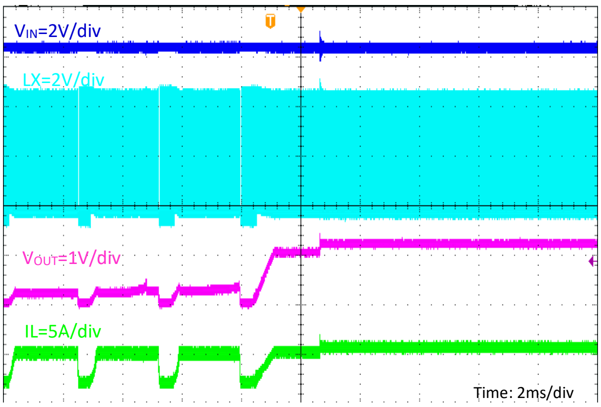
Output Short Entry

V_{IN} =5V, V_{OUT} =1.2V, I_o =3A



Output Short Recovery

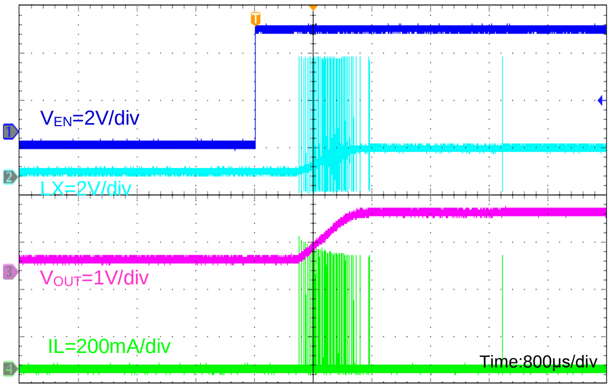
V_{IN}=5V, V_{OUT} =1.2V, I_o = 3A



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

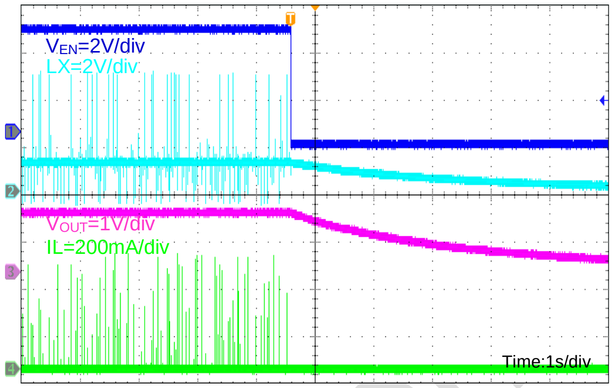
EN Enable Power On

V_{IN} =5V, V_{OUT} =1.2V, No Load



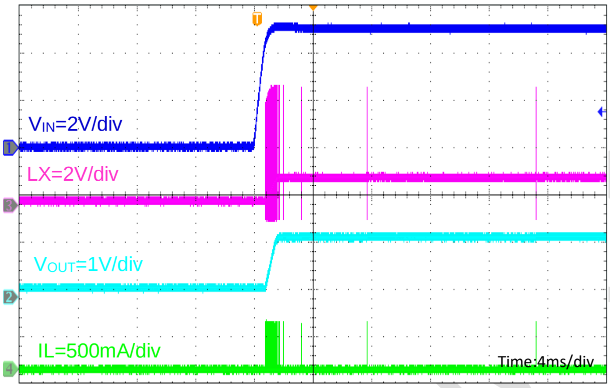
EN Disable Power down

V_{IN} =5V, V_{OUT} =1.2V, No Load



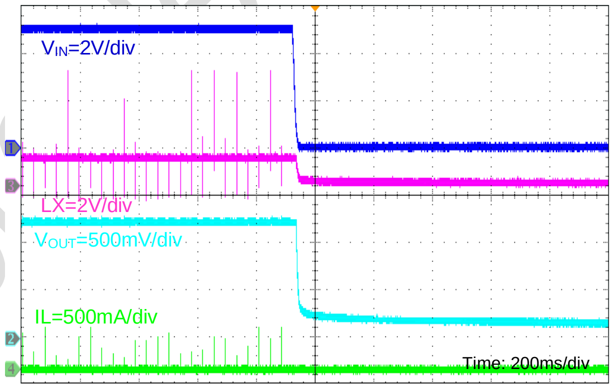
Input Power On

V_{IN} =5V, V_{OUT} =1.2V, No Load



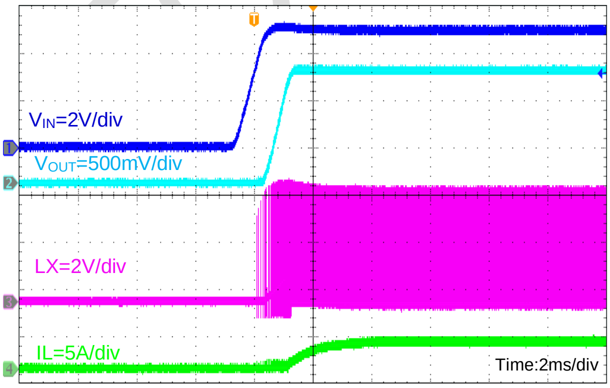
Input Power Down

V_{IN} =5V, V_{OUT} =1.2V, No Load



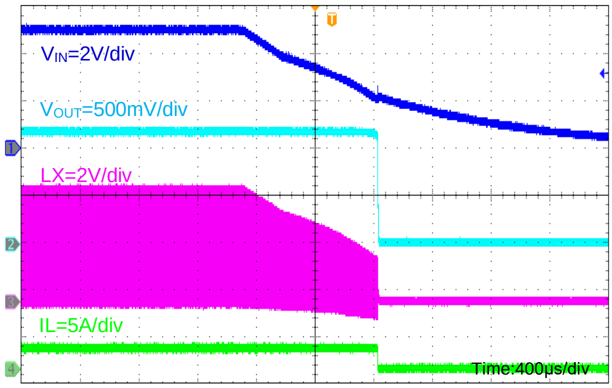
Input Power On

V_{IN} =5V, V_{OUT} =1.2V, I_o =3A



Input Power Down

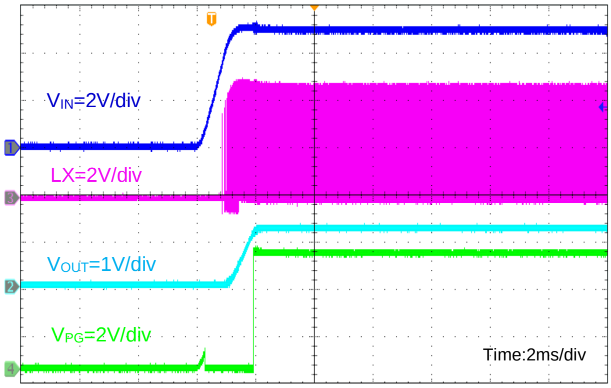
V_{IN} =5V, V_{OUT} =1.2V, I_o =3A



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

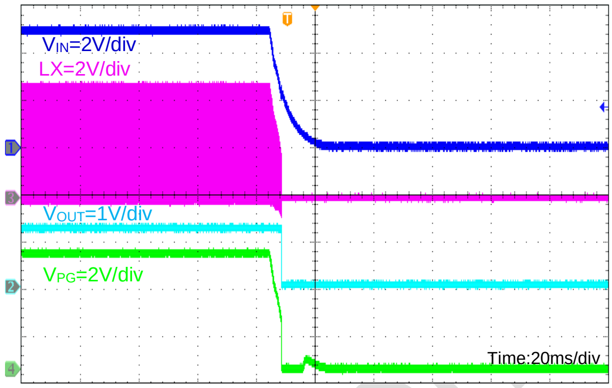
PG when Input Power On

V_{IN} =5V, V_{OUT} =1.2V, No Load



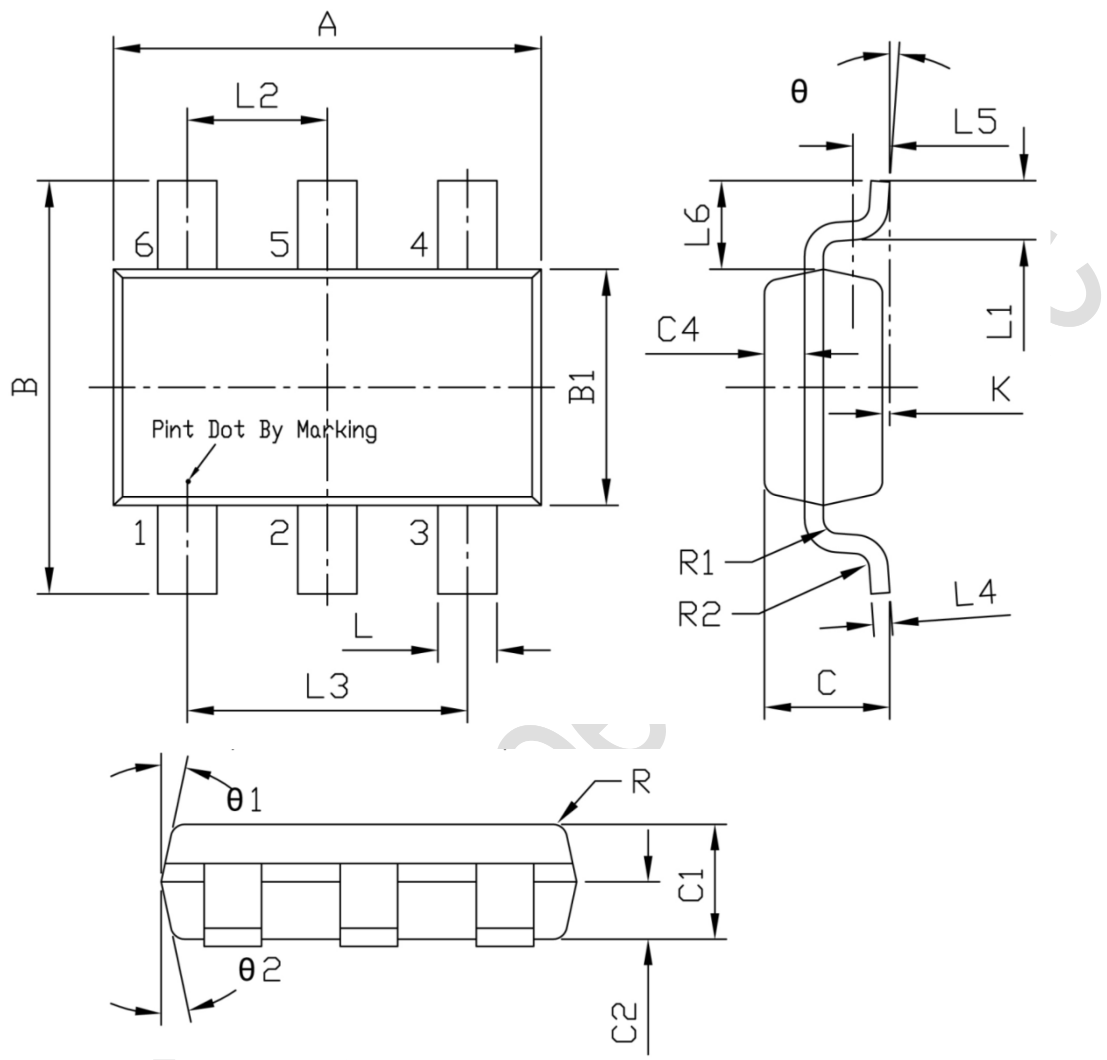
PG when Input Power Down

V_{IN} =5V, V_{OUT} =1.2V, No Load



PACKAGE INFORMATION

SOT23-6

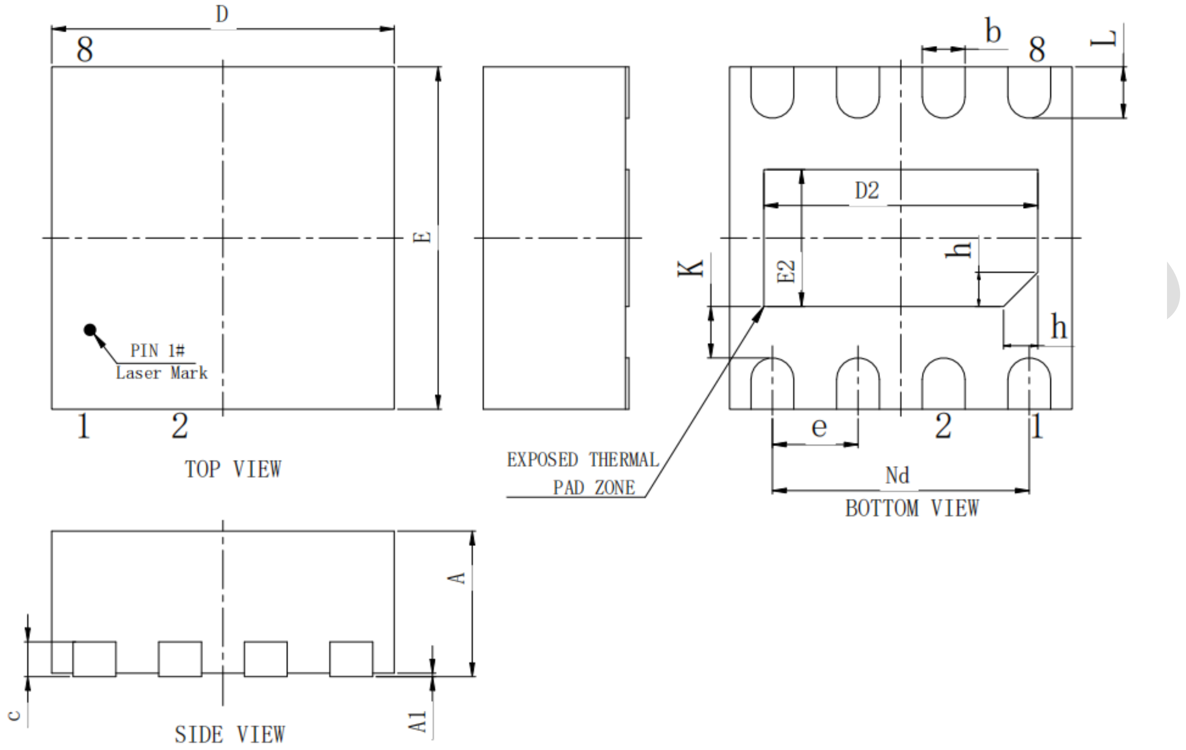


Unit: mm

Symbol	Dimensions In Millimeters			Symbol	Dimensions In Millimeters		
	Min	Typ	Max		Min	Typ	Max
A	2.80	2.90	3.00	L3	1.800	1.900	2.000
B	2.60	2.80	3.00	L4	0.077	0.127	0.177
B1	1.50	1.60	1.70	L5	-	0.250	-
C	-	-	1.05	L6	-	0.600	-
C1	0.60	0.80	1.00	θ	0°		0°
C2	0.35	0.40	0.45	Θ1	10°	12°	14°
C4	0.223	0.273	0.323	Θ2	10°	12°	14°
K	0.000	0.075	0.150	R	-	0.100	-
L	0.325	0.400	0.475	R1	-	0.100	-
L1	0.325	0.450	0.550	R2	-	0.100	-
L2	0.850	0.950	1.050				

PACKAGE INFORMATION

DFN2x2-8



Unit: mm

Symbol	Dimensions In Millimeters			Symbol	Dimensions In Millimeters		
	Min	Typ	Max		Min	Typ	Max
A	0.70	0.75	0.80	Nd	1.50 BSC		
A1	0	0.02	0.05	E2	0.75	0.80	0.85
c	0.203REF			e	0.50 BSC		
b	0.20	0.25	0.30	L	0.25	0.30	0.35
D	1.95	2.00	2.05	K	0.25	0.30	0.35
E	1.95	2.00	2.05	h	0.20REF		
D2	1.55	1.60	1.65	/	/		

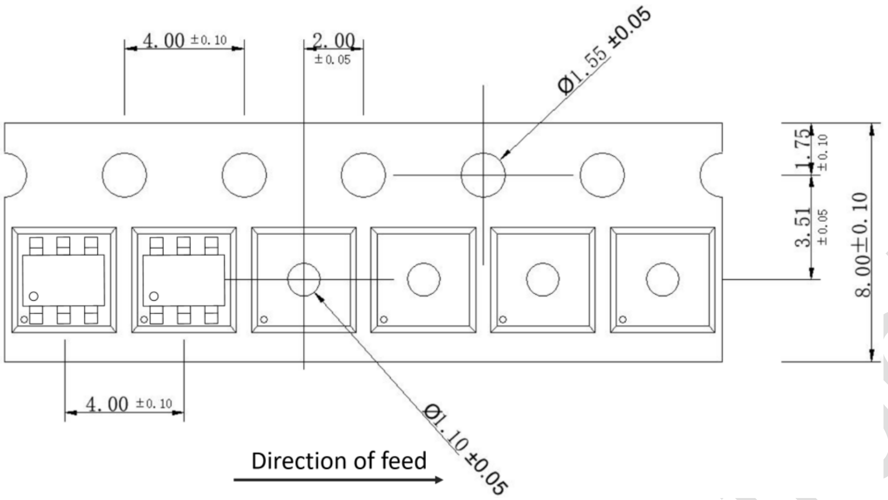
Note:

1) All dimensions are in millimeters.

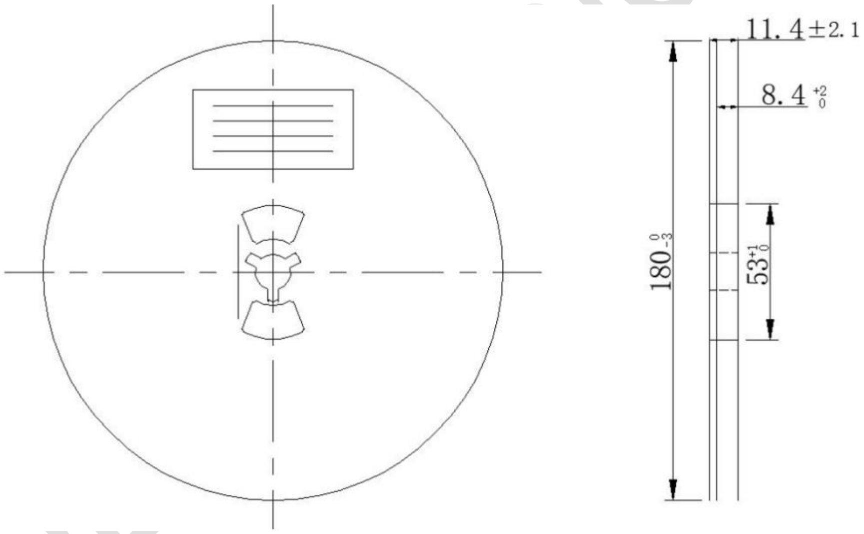
拓尔微电子
TOLL Microelectronic

TAPE AND REEL INFORMATION

TAPE DIMENSIONS: SOT23-6



REEL DIMENSIONS: SOT23-6

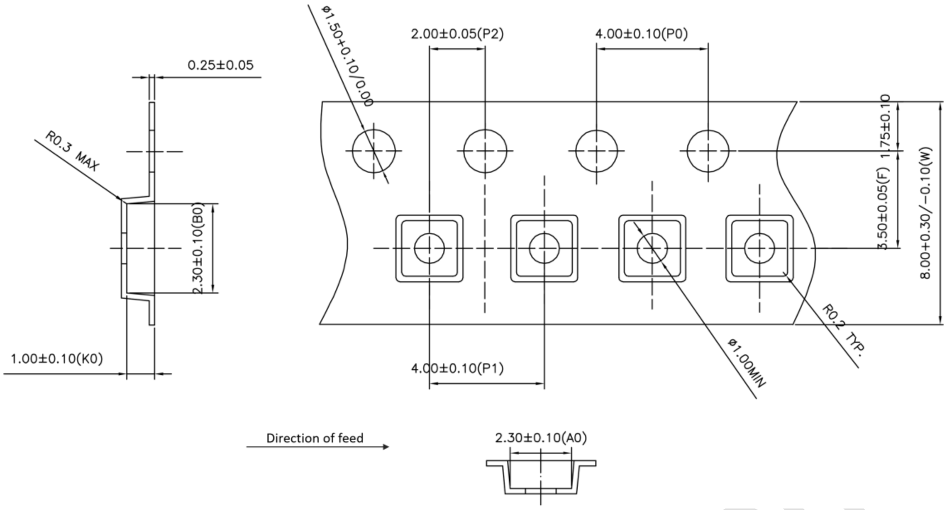


Note:

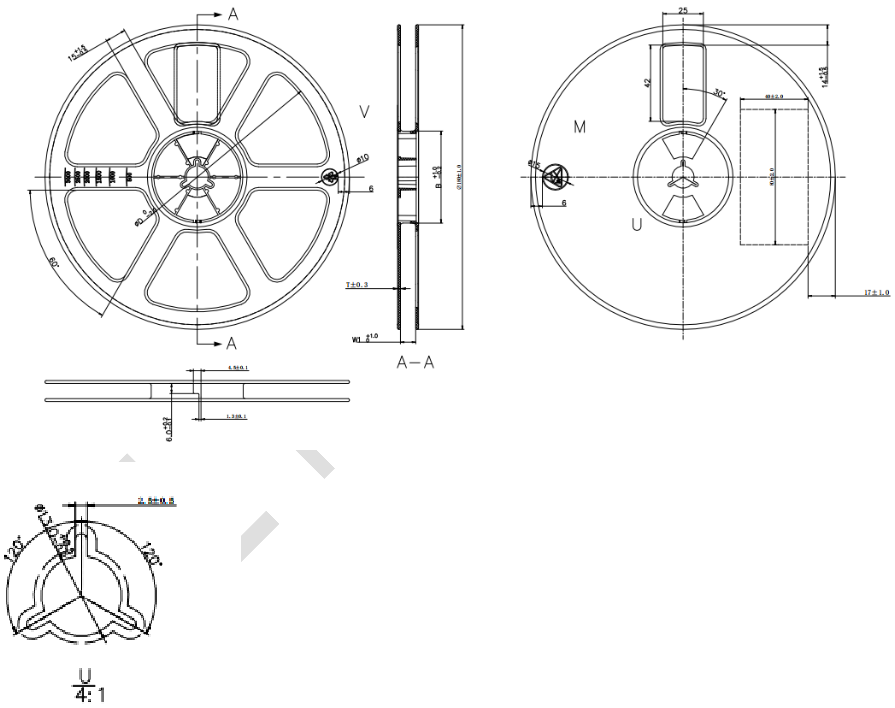
1) All Dimensions are in Millimeter
2) Quantity of Units per Reel is 3000
3) MSL level is level 3.

TAPE AND REEL INFORMATION

TAPE DIMENSIONS: DFN2x2-8



REEL DIMENSIONS: DFN2x2-8



Unit: mm

TAPE WIDTH	B	W1	T	150
8MM	54.4	8.6	1.4	14.4

Note:

1) All Dimensions are in Millimeter
2) Quantity of Units per Reel is 3000
3) MSL level is level 3.

Important Notification

This document only provides product information. TOLL Microelectronic Inc. reserves the right to make corrections, modifications, enhancements, improvements, and other changes to its products and to discontinue any product without notice at any time.

TOLL Microelectronic Inc. cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a TOLL Microelectronic Inc. product. No circuit patent licenses are implied.